

February 1986

# DS1648/DS3648/DS1678/DS3678 TRI-STATE® TTL to MOS Multiplexers/Drivers

## **General Description**

The DS1648/DS3648 and DS1678/DS3678 are quad 2-input multiplexers with TRI-STATE outputs designed to drive the large capacitive loads (up to 500 pF) associated with MOS memory systems. A PNP input structure is employed to minimize input currents so that driver loading in large memory systems is reduced. The circuit employs Schottky-clamped transistors for high speed and TRI-STATE outputs for bus operation.

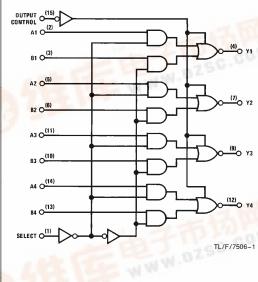
The DS1648/DS3648 has a 15 $\Omega$  resistor in series with the outputs to dampen transients caused by the fast-switching

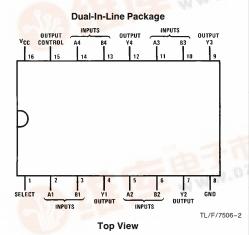
output. The DS1678/DS3678 has a direct, low impedance output for use with or without an external resistor.

#### **Features**

- $\hfill \blacksquare$  TRI-STATE outputs interface directly with system-bus
- Schottky-clamped for better ac performance
- PNP inputs to minimize input loading
- TTL compatible
- High-speed capacitive load drivers
- Built-in damping resistor (DS1648/DS3648 only)

## **Logic and Connection Diagrams**





Order Number DS1648J, DS3648J, DS1678J DS3678J, DS3648N or DS3678N See NS Package Number J16A or N16A

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### **Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage 7V
Logical "1" Input Voltage 7V
Logical "0" Input Voltage -1.5V

Maximum Power Dissipation\* at 25°C

Storage Temperature Range

Cavity Package 1433 mW
Molded Package 1362 mW

 $-65^{\circ}$ C to  $+150^{\circ}$ C

Lead Temperature

(Soldering, 10 seconds) 300°C

\* Derate cavity package 9.6 mW/°C above 25°C; derate molded package 10.9 mW/°C above 25°C.

	Min	Max	Units
Supply Voltage (V <sub>CC</sub> )	4.5	5.5	V
Temperature (T <sub>A</sub> )			
DS1648, DS1678	-55	+125	°C

+70

°C

**Operating Conditions** 

DS3648, DS3678

## Electrical Characteristics (Notes 2 and 3)

Symbol	Parameter	Conditions		Min	Тур	Max	Units	
V <sub>IN(1)</sub>	Logical "1" Input Voltage			2.0			٧	
V <sub>IN(0)</sub>	Logical "0" Input Voltage						0.8	٧
I <sub>IN(1)</sub>	Logical "1" Input Current	V <sub>CC</sub> = 5.5V, V <sub>IN</sub> = 5.5V				0.1	40	μΑ
I <sub>IN(0)</sub>	Logical "0" Input Current	$V_{CC} = 5.5V, V_{IN} = 0.5V$			-50	-250	μΑ	
V <sub>CLAMP</sub>	Input Clamp Voltage	$V_{CC} = 4.5V, I$	$I_{IN} = -18 \text{ mA}$			-0.75	-1.2	٧
V <sub>OH</sub>	Logical "1" Output Voltage	$V_{CC} = 4.5V, I$	$OH = -10 \mu A$	DS1648/DS1678	2.7	3.6		٧
	(No Load)	DS3648/E		DS3648/DS3678	2.8	3.6		٧
V <sub>OL</sub>	Logical "0" Output Voltage			DS1648/DS1678		0.25	0.4	٧
	(No Load)			DS3648/DS3678		0.25	0.35	٧
V <sub>OH</sub> Logical "1" Output Voltage		$V_{CC} = 4.5V, I_{OH} = -1.0 \text{ mA}$ DS1648		2.4	3.5		٧	
(With Load)	(With Load)	DS1678  DS3648  DS3678		2.5	3.5		٧	
				DS3648	2.6	3.5		٧
				DS3678	2.7	3.5		٧
V <sub>OL</sub>	Logical "0" Output Voltage	"0" Output Voltage V <sub>CC</sub> = 4.5V, I <sub>OL</sub> = 20 mA		DS1648		0.6	1.1	٧
	(With Load)			DS1678		0.4	0.5	٧
				DS3648		0.6	1.0	٧
				DS3678		0.4	0.5	V
I <sub>1D</sub>	Logical "1" Drive Current	V <sub>CC</sub> = 4.5V, V <sub>OUT</sub> = 0V, (Note 4)				-250		mA
I <sub>0D</sub>	Logical "0" Drive Current	V <sub>CC</sub> = 4.5V, V <sub>OUT</sub> = 4.5V, (Note 4)				150		mA
I <sub>Hi-Z</sub>	TRI-STATE Output Current	V <sub>OUT</sub> = 0.4V to 2.4V, Output Control = 2.0V			-40		40	μΑ
Icc	Power Supply Current	V <sub>CC</sub> = 5.5V	Output Control All Other Inputs			42	60	mA
			All Inputs at 0V			20	32	mA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

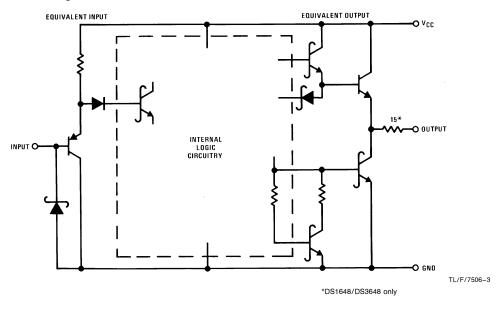
Note 2: Unless otherwise specified min/max limits apply across the  $-55^{\circ}$ C to  $+125^{\circ}$ C temperature range for the DS1648 and DS1678 and across the  $0^{\circ}$ C to  $+70^{\circ}$ C range for the DS3648 and DS3678. All typical values for  $T_A = 25^{\circ}$ C and  $V_{CC} = 5V$ .

Note 3: All currents into device pins shown as positive, out of device pins as negative, all voltages referenced to ground unless otherwise noted. All values shown as max or min on absolute value basis.

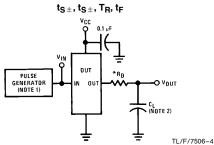
Note 4: When measuring output drive current and switching response for the DS1678 and DS3678 a  $15\Omega$  resistor should be placed in series with each output. This resistor is internal to the DS1648/DS3648 and need not be added.

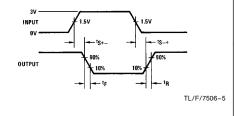
Symbol	Parameter	Conditions		Min	Тур	Max	Units
$t_{S\pm}$	Storage Delay Negative Edge	(Figure 1)	$C_L = 50 pF$		5	7	ns
			$C_L = 500  pF$		9	12	ns
$t_{S^{\mp}}$	Storage Delay Positive Edge	(Figure 1)	$C_L = 50 pF$		6	8	ns
			$C_L = 500  pF$		9	13	ns
$t_{F}$	Fall Time	(Figure 1)	$C_L = 50  pF$		5	8	ns
			$C_L = 500  pF$		22	35	ns
$t_{R}$	Rise Time	(Figure 1)	$C_L = 50  pF$		6	9	ns
			$C_L = 500  pF$		22	35	ns
$t_{ZL}$	Delay from Output Control Input to Logical "0" Level (from High Impedance State)	$C_L = 50 \text{ pF}, R_L = 2 \text{ k}\Omega \text{ to V}_{CC},$ (Figure 2)			10	15	ns
t <sub>ZH</sub>	Delay from Output Control Input to Logical "1" Level (from High Impedance State)	$C_L = 50 \text{ pF}, R_L = 2 \text{ k}\Omega \text{ to GND}$ (Figure 2)			8	15	ns
$t_{LZ}$	Delay from Output Control Input to High Impedance State (from Logical "0" Level)	$C_L = 50 \text{ pF}, R_L = 400\Omega \text{ to V}_{CC},$ (Figure 3)			15	25	ns
t <sub>HZ</sub>	Delay from Output Control Input to High Impedance State (from Logical "1" Level)	$C_L = 50 \text{ pF}, R_L = 400\Omega \text{ to GND},$ (Figure 3)			10	25	ns
t <sub>S±</sub>	Propagation Delay to Logical "0" Transition When Select Selects A	C <sub>L</sub> = 50 pF, (Figure 1)			12	15	ns
t <sub>S∓</sub>	Propagation Delay to Logical "1" Transition When Select Selects A	C <sub>L</sub> = 50 pF, (Figure 1)			14	17	ns
t <sub>S±</sub>	Propagation Delay to Logical "0" Transition When Select Selects B	C <sub>L</sub> = 50 pF, (Figure 1)			16	20	ns
t <sub>S</sub> ∓	Propagation Delay to Logical "1" Transition When Select Selects B	C <sub>L</sub> = 50 pF, (Figure 1)			14	20	ns

# **Schematic Diagram**



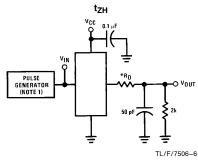
# **AC Test Circuits and Switching Time Waveforms**

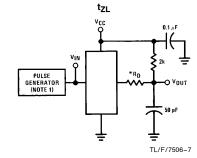


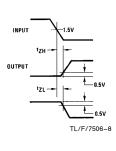


Note 1: The pulse generator has the following characteristics:  $Z_{OUT} = 50\Omega$  and PRR  $\le 1$  MHz. Rise and fall times between 10% and 90% points  $\le 5$  ns. Note 2: C<sub>L</sub> includes probe and jig capacitance.

### FIGURE 1

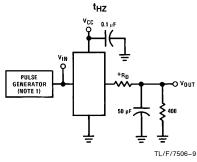


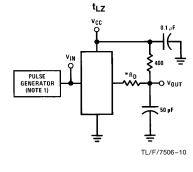


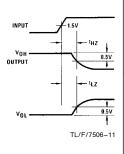


\*Internal on DS1648 and DS3648

FIGURE 2







\*Internal on DS1648 and DS3648

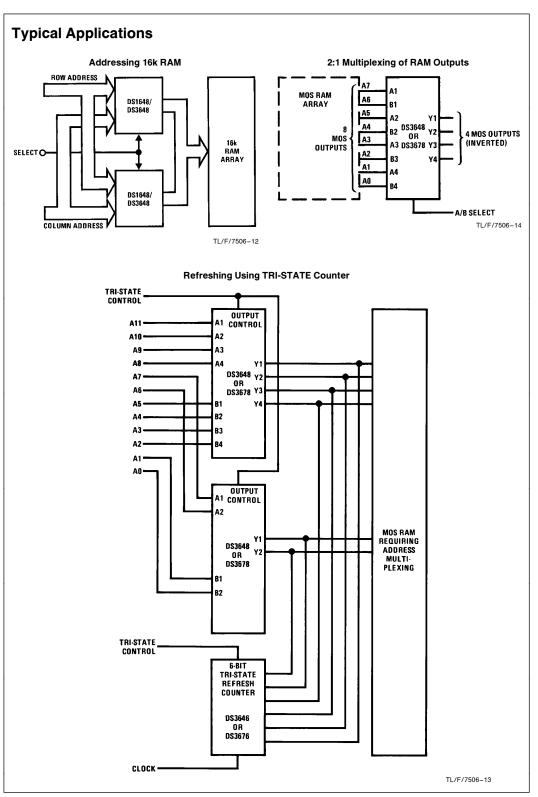
FIGURE 3

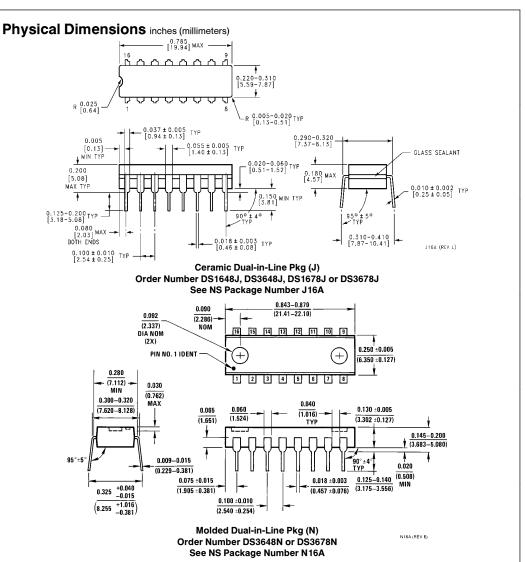
## **Truth Table**

Output	l:	Outputs		
Control	Select	Α	В	Outputs
Н	Х	Х	Х	Hi-Z
L	L	L	Χ	Н
L	L	Н	Χ	L
L	Н	X	L	Н
L	Н	X	Н	L

 $\begin{array}{ll} H = \mbox{High level} \\ L = \mbox{Low level} \\ X = \mbox{Don't care} \end{array}$ 

Hi-Z = TRI-STATE mode





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